

DATA SHEET

74LVC2GU04 Dual inverter

Product specification

2003 Aug 29

Dual inverter

74LVC2GU04

FEATURES

- Wide supply voltage range from 1.65 to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
 - JESD8-7 (1.65 to 1.95 V)
 - JESD8-5 (2.3 to 2.7 V)
 - JESD8B/JESD36 (2.7 to 3.6 V).
- ESD protection:
 - HBM EIA/JESD22-A114-A exceeds 2000 V
 - MM EIA/JESD22-A115-A exceeds 200 V.
- ± 24 mA output drive ($V_{CC} = 3.0$ V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- SOT363 and SOT457 packages
- Specified from -40 to $+125$ °C.

DESCRIPTION

The 74LVC2GU04 is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Input can be driven from either 3.3 or 5 V devices. These features allow the use of these devices in a mixed 3.3 and 5 V environment.

The 74LVC2GU04 provides two inverters. Each inverter is a single stage with unbuffered output.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25$ °C.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	propagation delay inputs nA to output nY	$V_{CC} = 1.8$ V; $C_L = 30$ pF; $R_L = 1$ k Ω	2.3	ns
		$V_{CC} = 2.5$ V; $C_L = 30$ pF; $R_L = 500$ Ω	1.8	ns
		$V_{CC} = 2.7$ V; $C_L = 50$ pF; $R_L = 500$ Ω	2.6	ns
		$V_{CC} = 3.3$ V; $C_L = 50$ pF; $R_L = 500$ Ω	2.3	ns
		$V_{CC} = 5.0$ V; $C_L = 50$ pF; $R_L = 500$ Ω	1.7	ns
C_I	input capacitance		5	pF
C_{PD}	power dissipation capacitance per gate	$V_{CC} = 3.3$ V; notes 1 and 2	13.5	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

$\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

2. The condition is $V_I = \text{GND to } V_{CC}$.

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FUNCTION TABLE

See note 1.

INPUT	OUTPUT
nA	nY
L	H
H	L

Note

1. H = HIGH voltage level;
L = LOW voltage level.

ORDERING INFORMATION

TYPE NUMBER	PACKAGES					
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE	MARKING
74LVC2GU04GW	−40 to +125 °C	6	SC-88	plastic	SOT363	YD
74LVC2GU04GV	−40 to +125 °C	6	SC-74	plastic	SOT457	VU4

PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	GND	ground (0 V)
3	2A	data input
4	2Y	data output
5	V _{CC}	supply voltage
6	1Y	data output

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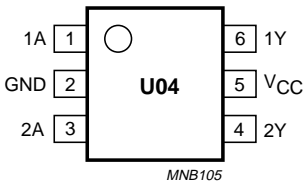


Fig.1 Pin configuration.

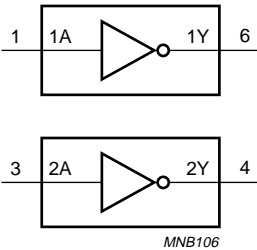


Fig.2 Logic symbol.

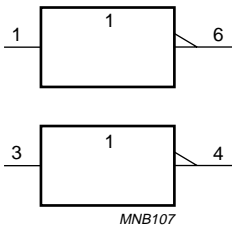


Fig.3 IEC logic symbol.

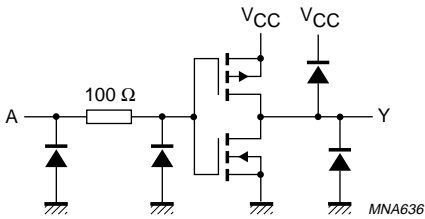


Fig.4 Logic diagram (one gate).

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		1.65	5.5	V
V_I	input voltage		0	5.5	V
V_O	output voltage	active mode	0	V_{CC}	V
		$V_{CC} = 0$ V; Power-down mode	0	5.5	V
T_{amb}	operating ambient temperature		-40	+125	°C
t_r, t_f	input rise and fall times	$V_{CC} = 1.65$ to 2.7 V	0	20	ns/V
		$V_{CC} = 2.7$ to 5.5 V	0	10	ns/V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		-0.5	+6.5	V
I_{IK}	input diode current	$V_I < 0$	-	-50	mA
V_I	input voltage	note 1	-0.5	+6.5	V
I_{OK}	output diode current	$V_O > V_{CC}$ or $V_O < 0$	-	±50	mA
V_O	output voltage	active mode; notes 1 and 2	-0.5	$V_{CC} + 0.5$	V
		Power-down mode; notes 1 and 2	-0.5	+6.5	V
I_O	output source or sink current	$V_O = 0$ to V_{CC}	-	±50	mA
I_{CC}, I_{GND}	V_{CC} or GND current		-	±100	mA
T_{stg}	storage temperature		-65	+150	°C
P_D	power dissipation	$T_{amb} = -40$ to $+125$ °C	-	300	mW

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. When $V_{CC} = 0$ V (Power-down mode), the output voltage can be 5.5 V in normal operation.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP. ⁽¹⁾	MAX.	UNIT
		OTHER	V _{CC} (V)				
T _{amb} = −40 to +85 °C							
V _{IH}	HIGH-level input voltage		1.65 to 5.5	0.75 × V _{CC}	–	–	V
V _{IL}	LOW-level input voltage		1.65 to 5.5	–	–	0.25 × V _{CC}	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = 100 μA	1.65 to 5.5	–	–	0.1	V
		I _O = 4 mA	1.65	–	–	0.45	V
		I _O = 8 mA	2.3	–	–	0.3	V
		I _O = 12 mA	2.7	–	–	0.4	V
		I _O = 24 mA	3.0	–	–	0.55	V
		I _O = 32 mA	4.5	–	–	0.55	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = −100 μA	1.65 to 5.5	V _{CC} − 0.1	–	–	V
		I _O = −4 mA	1.65	1.2	–	–	V
		I _O = −8 mA	2.3	1.9	–	–	V
		I _O = −12 mA	2.7	2.2	–	–	V
		I _O = −24 mA	3.0	2.3	–	–	V
		I _O = −32 mA	4.5	3.8	–	–	V
I _{LI}	input leakage current	V _I = 5.5 V or GND	5.5	–	±0.1	±5	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	5.5	–	0.1	10	μA

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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP. ⁽¹⁾	MAX.	UNIT
		OTHER	V _{CC} (V)				
T _{amb} = −40 to +125 °C							
V _{IH}	HIGH-level input voltage		1.65 to 5.5	0.8 × V _{CC}	–	–	V
V _{IL}	LOW-level input voltage		1.65 to 5.5	–	–	0.2 × V _{CC}	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = 100 μA	1.65 to 5.5	–	–	0.1	V
		I _O = 4 mA	1.65	–	–	0.70	V
		I _O = 8 mA	2.3	–	–	0.45	V
		I _O = 12 mA	2.7	–	–	0.60	V
		I _O = 24 mA	3.0	–	–	0.80	V
		I _O = 32 mA	4.5	–	–	0.80	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}					
		I _O = −100 μA	1.65 to 5.5	V _{CC} − 0.1	–	–	V
		I _O = −4 mA	1.65	0.95	–	–	V
		I _O = −8 mA	2.3	1.7	–	–	V
		I _O = −12 mA	2.7	1.9	–	–	V
		I _O = −24 mA	3.0	2.0	–	–	V
		I _O = −32 mA	4.5	3.4	–	–	V
I _{LI}	input leakage current	V _I = 5.5 V or GND	5.5	–	–	±20	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	5.5	–	–	40	μA

Note

1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

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AC CHARACTERISTICS

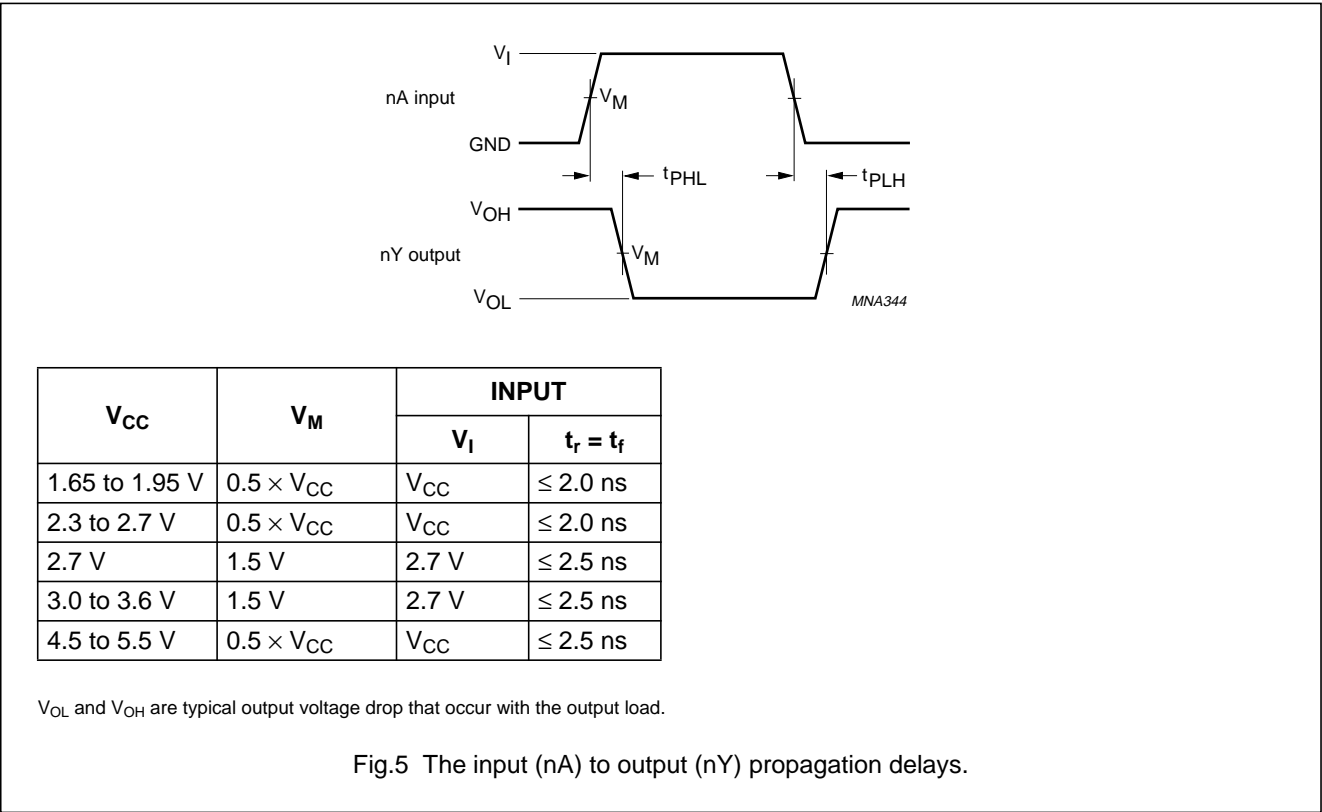
GND = 0 V.

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)				
T _{amb} = −40 to +85 °C; note 1							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 5 and 5	1.65 to 1.95	0.5	2.3	5.0	ns
			2.3 to 2.7	0.3	1.8	4.0	ns
			2.7	0.3	2.6	4.5	ns
			3.0 to 3.6	0.3	2.3	3.7	ns
			4.5 to 5.5	0.3	1.7	3.0	ns
T _{amb} = −40 to +125 °C							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 5 and 5	1.65 to 1.95	0.5	—	6.3	ns
			2.3 to 2.7	0.3	—	5.0	ns
			2.7	0.3	—	5.6	ns
			3.0 to 3.6	0.3	—	4.5	ns
			4.5 to 5.5	0.3	—	3.8	ns

Note

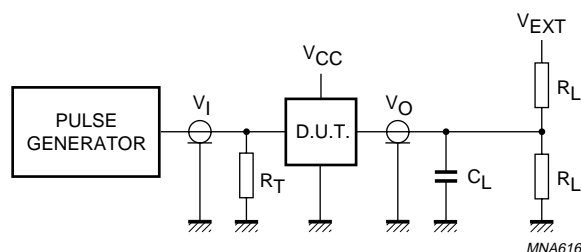
1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

AC WAVEFORMS



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V _{CC}	V _I	C _L	R _L	V _{EXT}
				t _{PLH} /t _{PHL}
1.65 to 1.95 V	V _{CC}	30 pF	1 kΩ	open
2.3 to 2.7 V	V _{CC}	30 pF	500 Ω	open
2.7 V	2.7 V	50 pF	500 Ω	open
3.0 to 3.6 V	2.7 V	50 pF	500 Ω	open
4.5 to 5.5 V	V _{CC}	50 pF	500 Ω	open

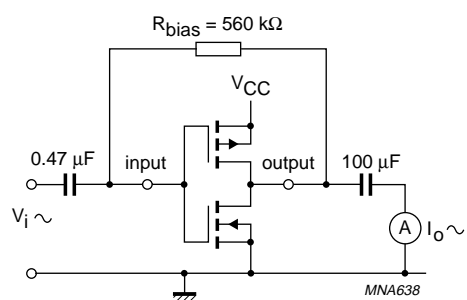
Definitions for test circuit:

R_L = Load resistor.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

Fig.5 Load circuitry for switching times.



$$G_{fs} = \frac{\Delta I_o}{\Delta V_i}$$

 $f_j = 1 \text{ kHz.}$

V_0 is constant.

Fig.6 Test set-up for measuring forward transconductance.

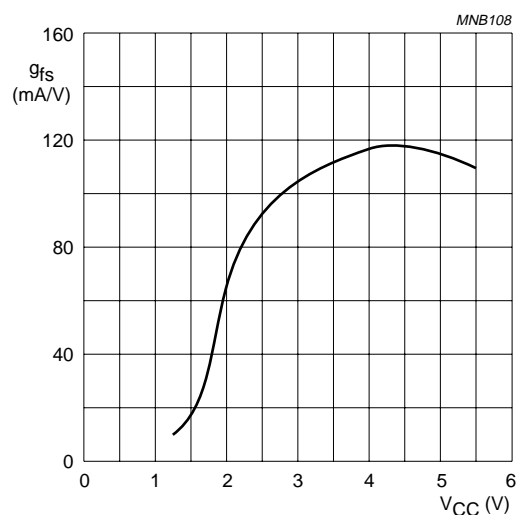
 $T_{amb} = 25\text{ }^{\circ}\text{C}.$

Fig.7 Typical forward transconductance as a function of supply voltage.

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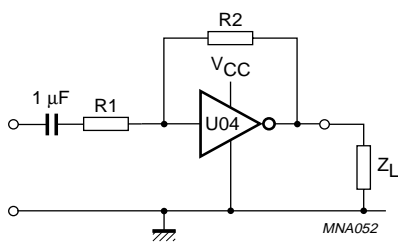
APPLICATION INFORMATION

Some applications for the 74LVC2GU04 are:

- Linear amplifier (see Fig.8)
- Crystal oscillator (see Fig.9).

Remark to the application information.

All values given are typical values unless otherwise specified.



$Z_L > 10 \text{ k}\Omega$, $R1 \geq 3 \text{ k}\Omega$ and $R2 \leq 1 \text{ M}\Omega$.

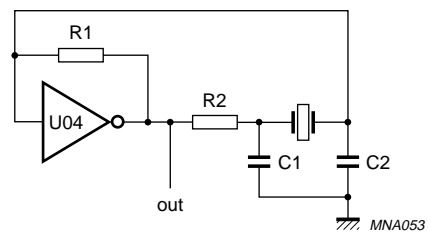
Open loop amplification: $A_{OL} = 20$ (typical value).

Voltage amplification: $A_u = -\frac{A_{OL}}{1 + \frac{R1}{R2}(1 + A_{OL})}$

Maximum output voltage: $V_{O(p-p)} = V_{CC} - 1.5 \text{ V}$ centered at $0.5V_{CC}$.

Unity gain bandwidth product: $B = 5 \text{ MHz}$ (typical value).

Fig.8 Used as a linear amplifier.



$C1 = 47 \text{ pF}$ (typical).

$C2 = 22 \text{ pF}$ (typical).

$R1 = 1 \text{ to } 10 \text{ M}\Omega$ (typical).

$R2$ optimum value depends on the frequency and required stability against changes in V_{CC} or average minimum I_{CC} ($I_{CC} = 2 \text{ mA}$ (typical) at $V_{CC} = 3.3 \text{ V}$ and $f = 10 \text{ MHz}$).

Fig.9 Crystal oscillator configuration.

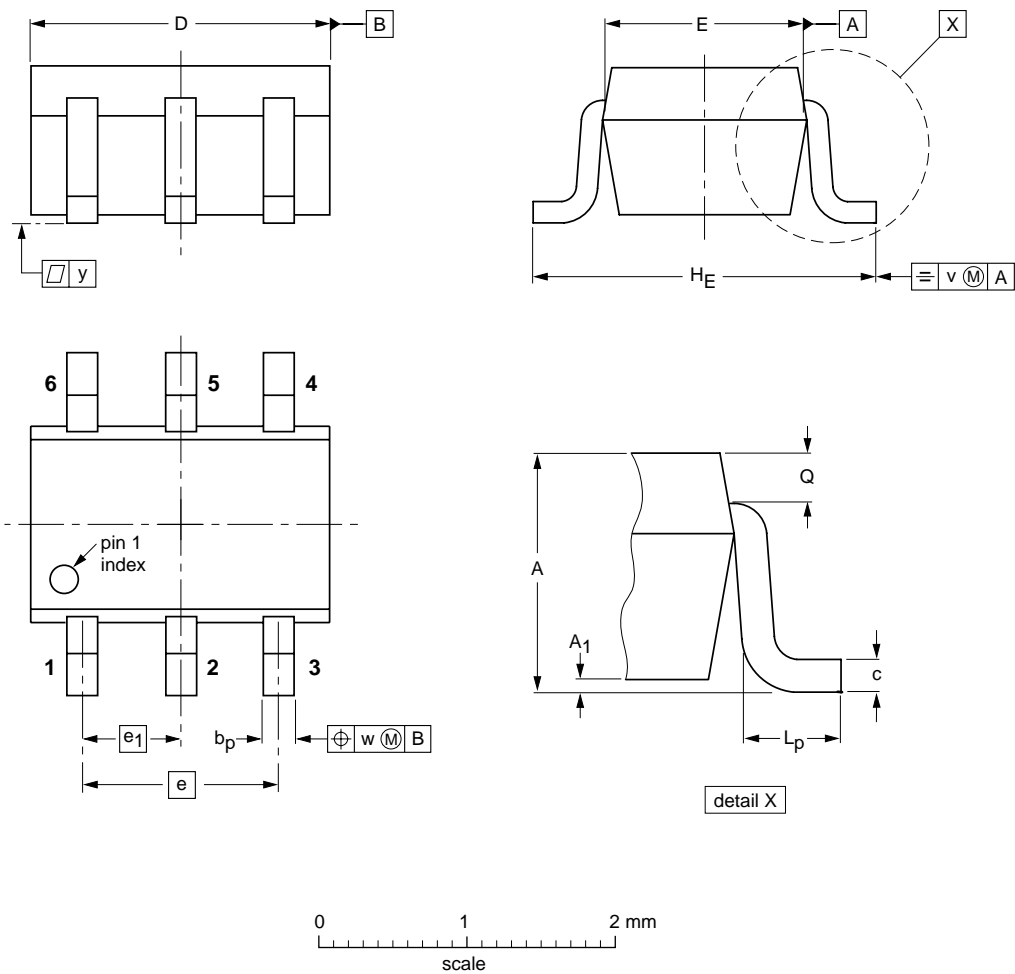
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PACKAGE OUTLINES

Plastic surface mounted package; 6 leads

SOT363



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w	y
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

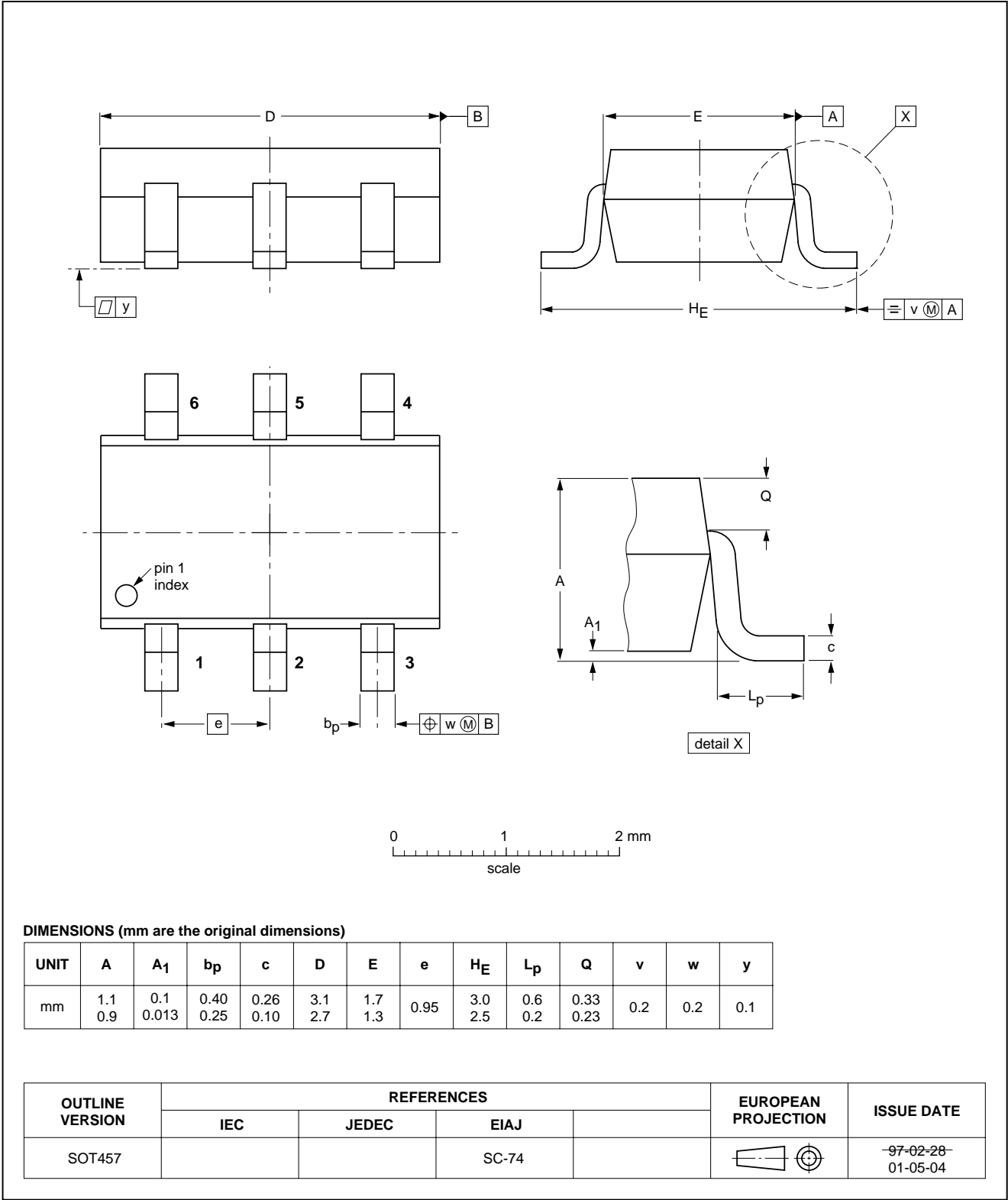
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT363			SC-88			97-02-28

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Plastic surface mounted package; 6 leads

SOT457



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LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
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Printed in The Netherlands

01/pp14

Date of release: 2003 Aug 29

Document order number: 9397 750 11717

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